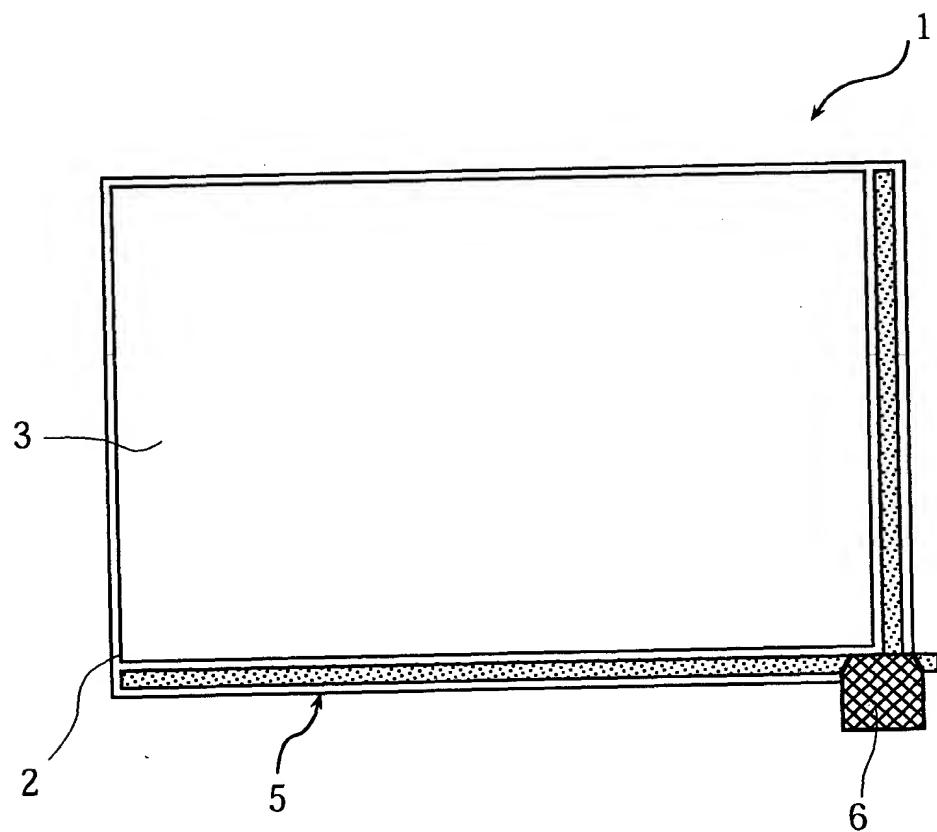


Fig. 1

TOP SECRET//REF ID: A65304



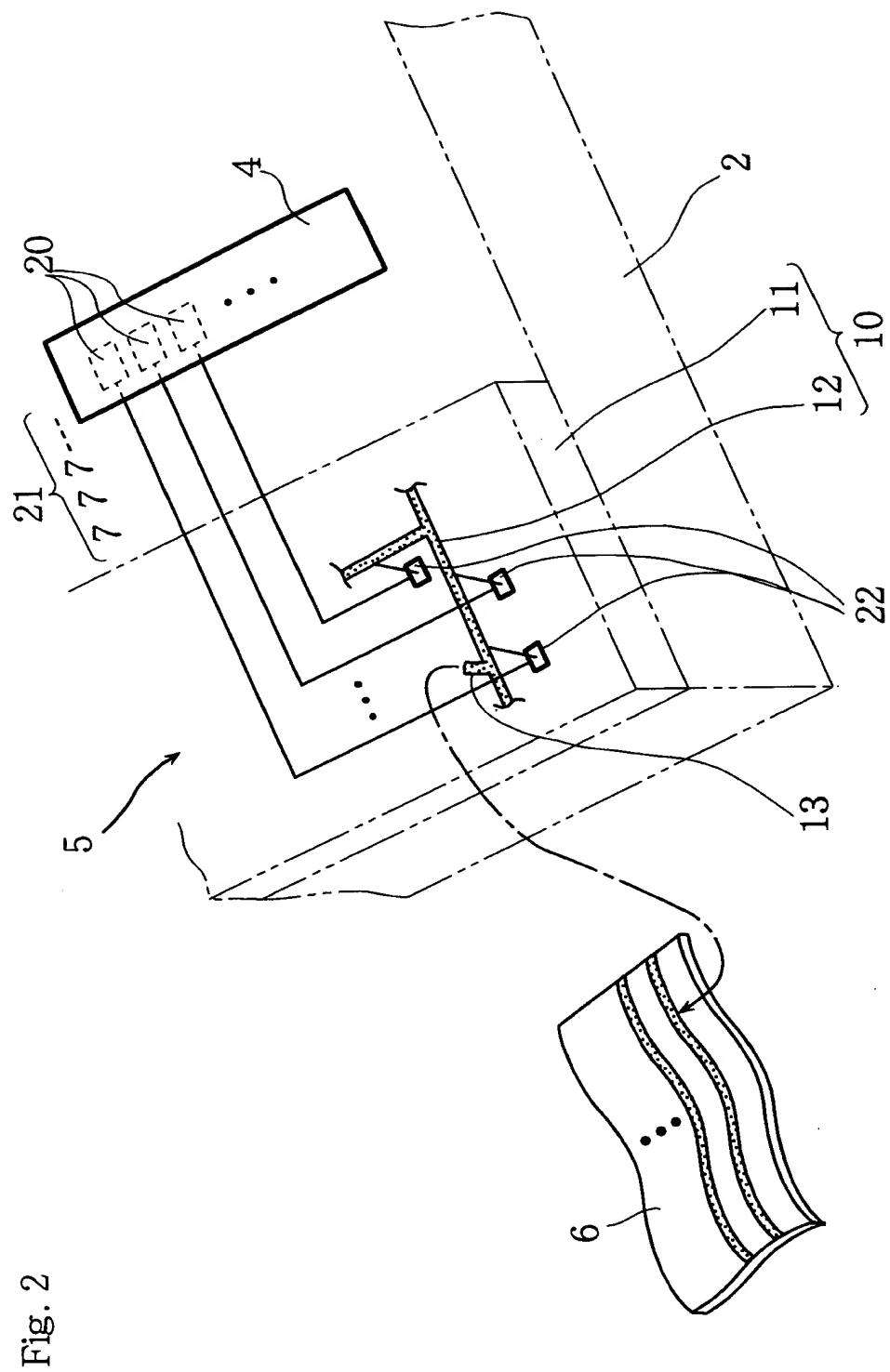


Fig. 2

Fig. 3

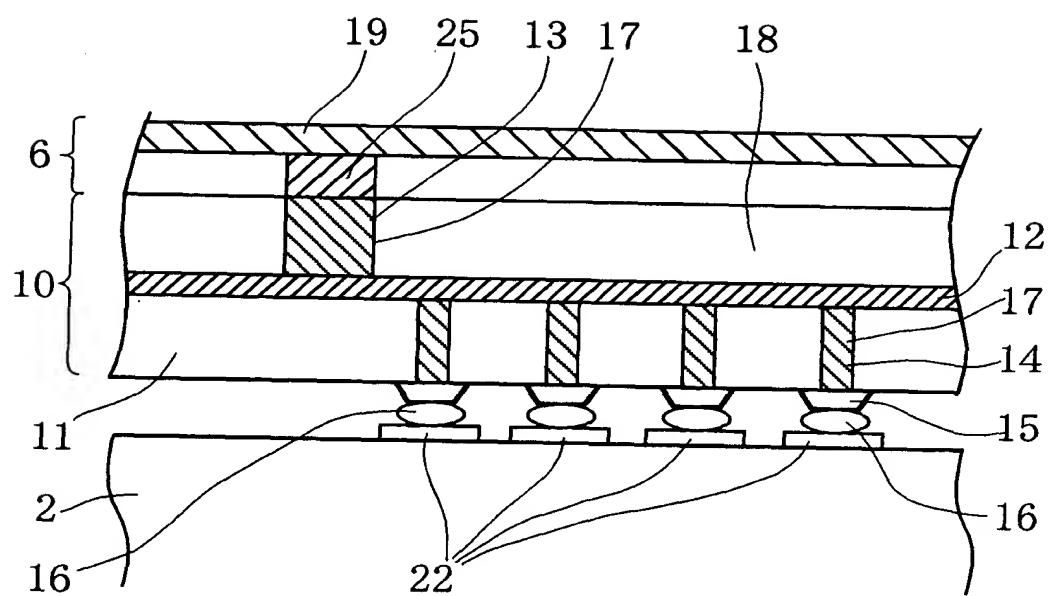


Fig. 4

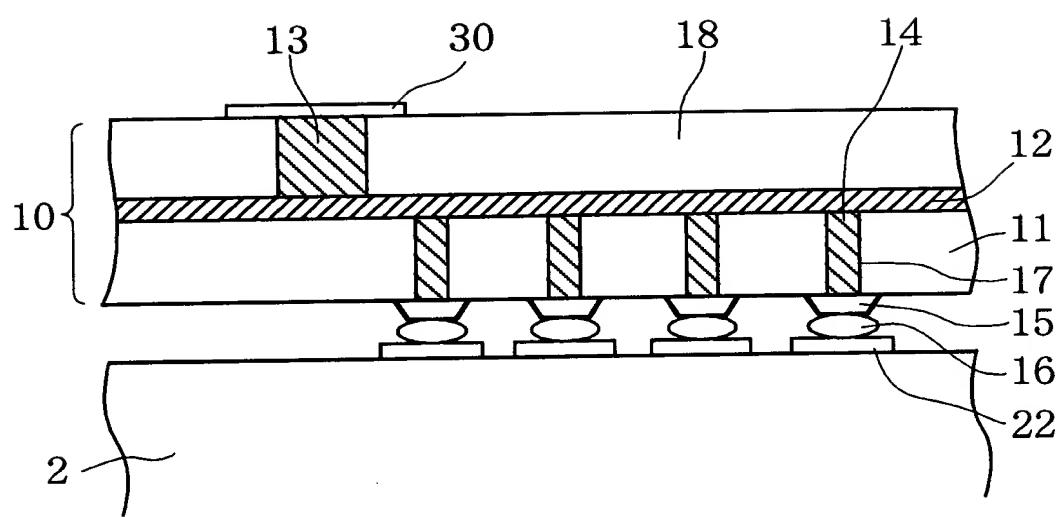
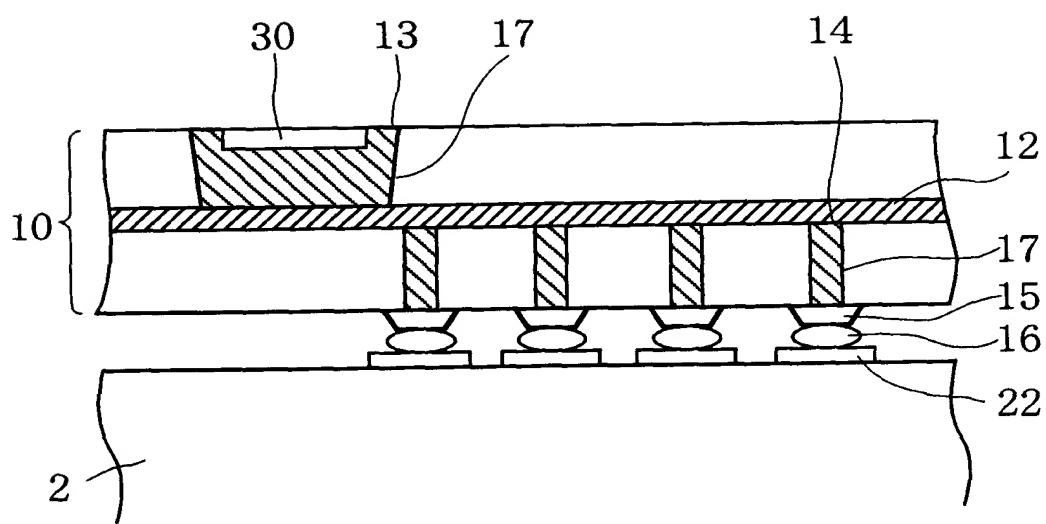
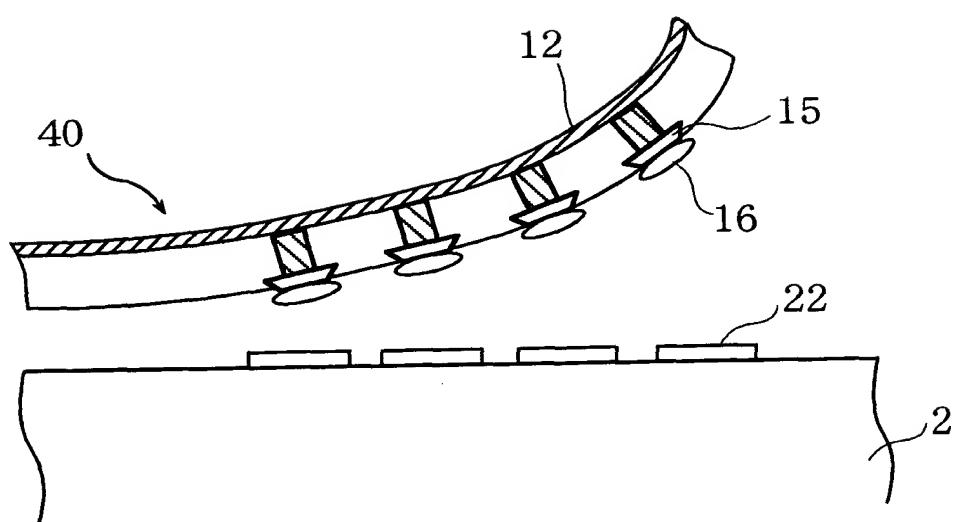


Fig. 5



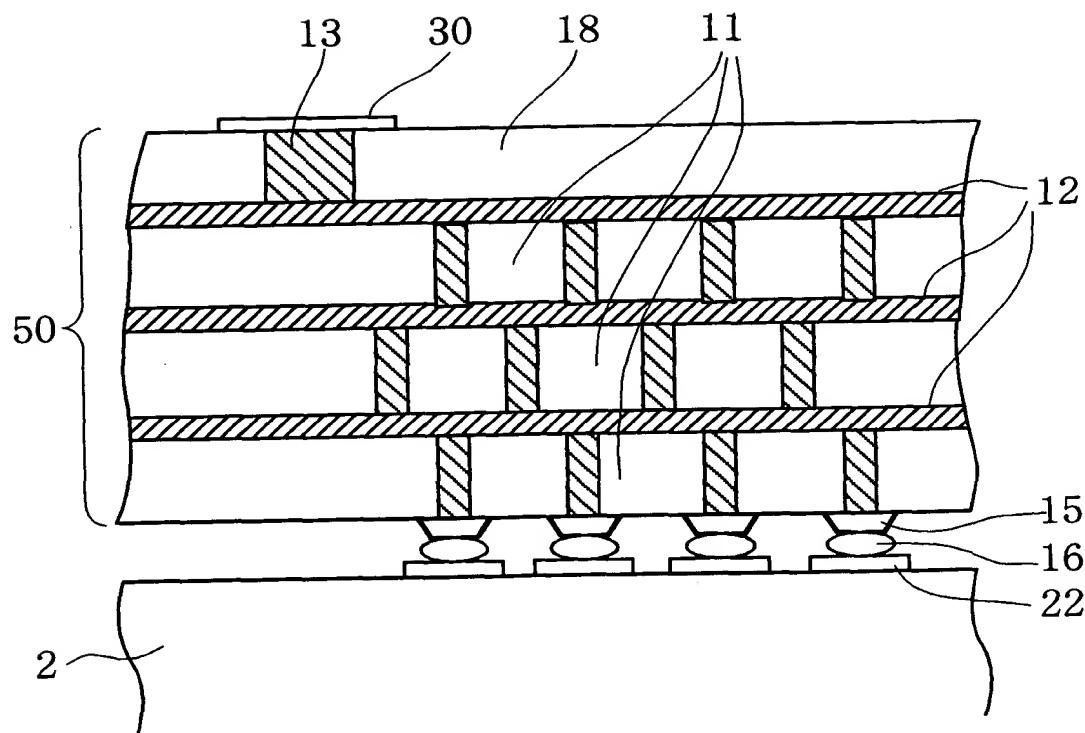
09/831315

Fig. 6



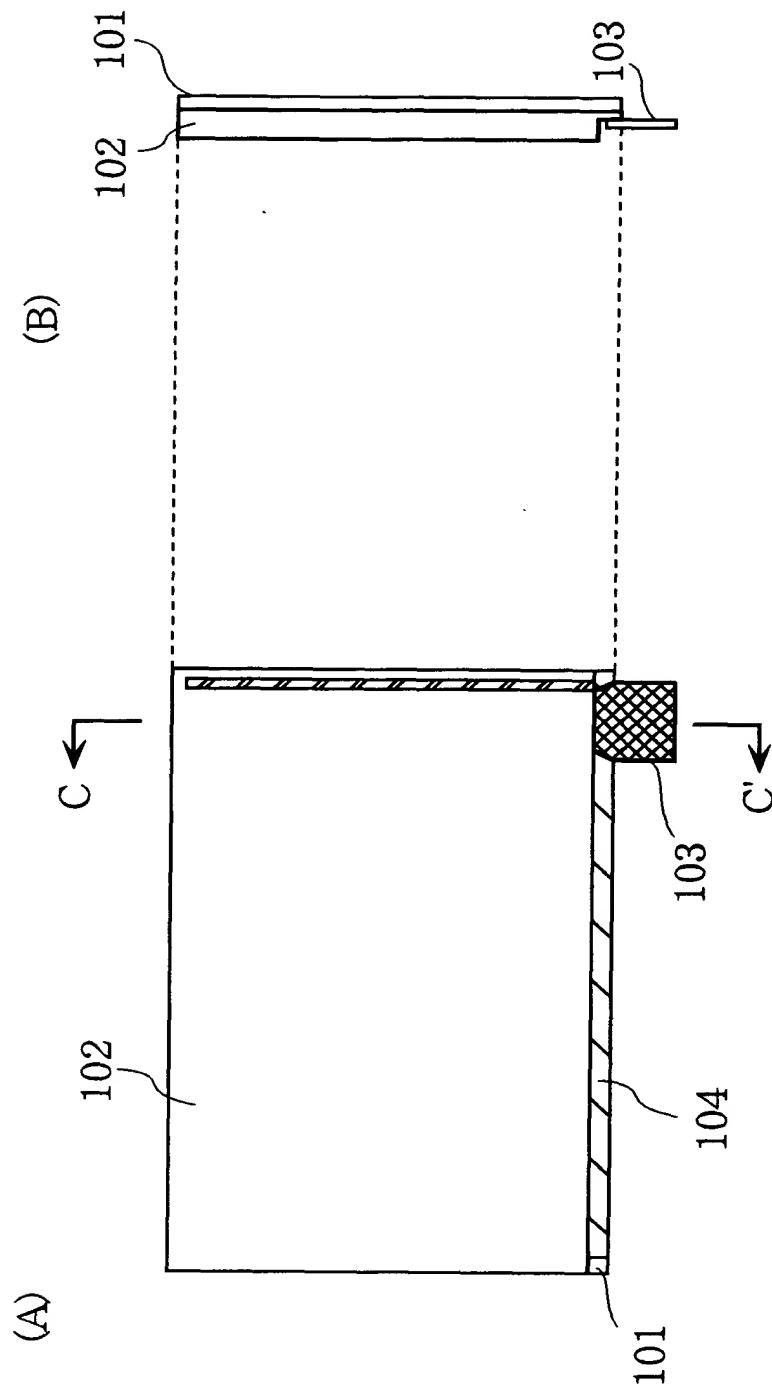
09/831315 090801

Fig. 7



09/831315 - 050001

Fig. 8



09/831315

TECHNICON SAFETY CARD

Fig. 9

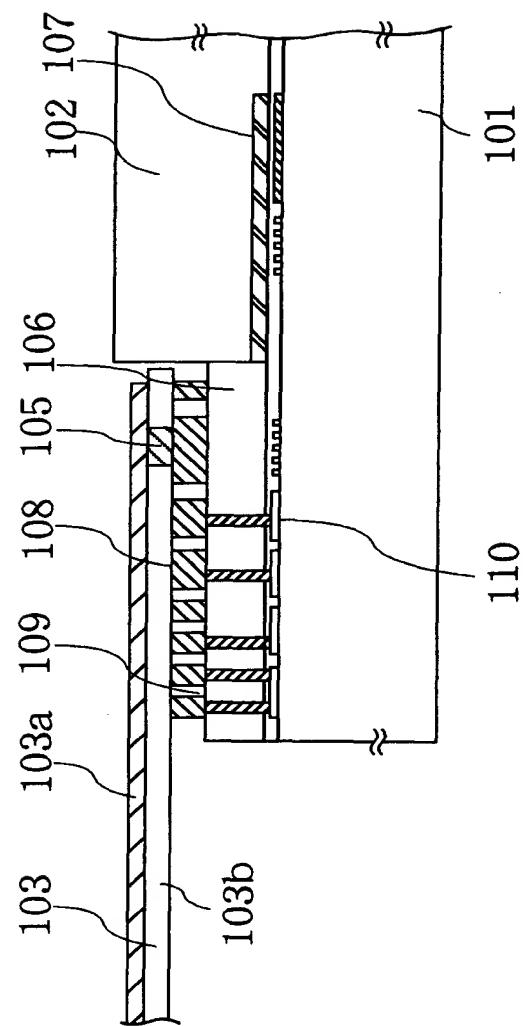
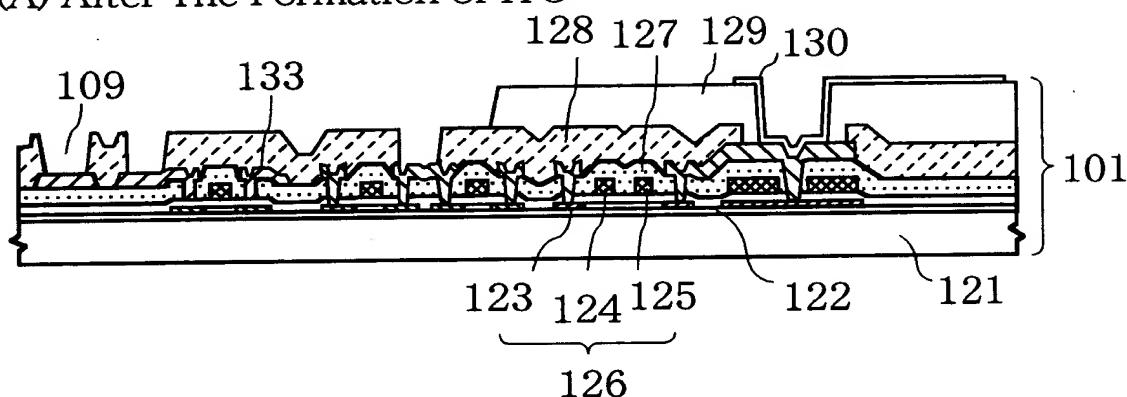
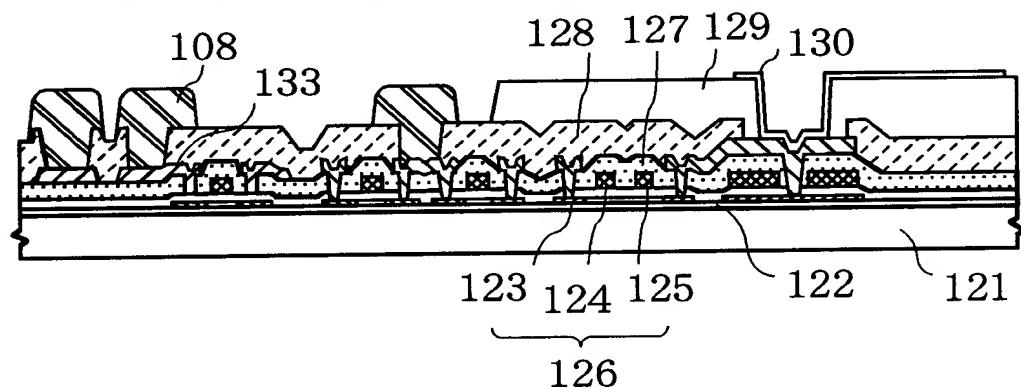


Fig. 10

(A) After The Formation of ITO



(B) After The Printing of Bus Line Electrode



(C) After The Formation of Printed Protective Film

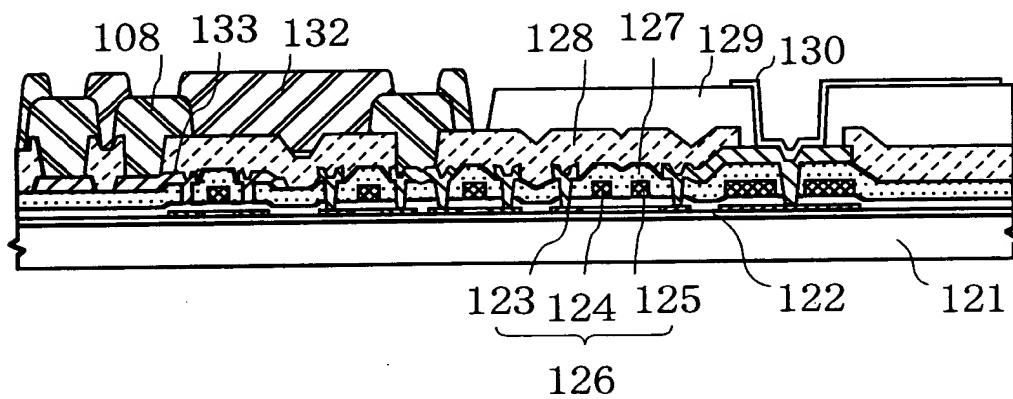
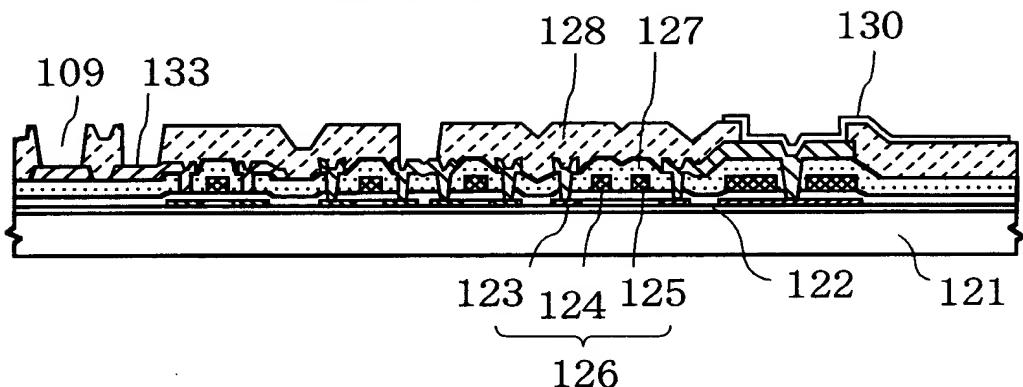
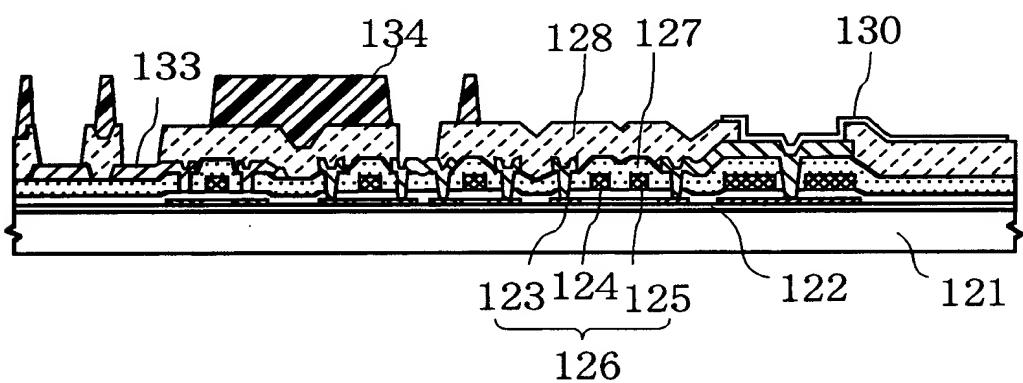


Fig. 11

(A) After The Formation of ITO



(B) After The Printing of Insulating Film



(C) After the Formation of Bus Line Electrode

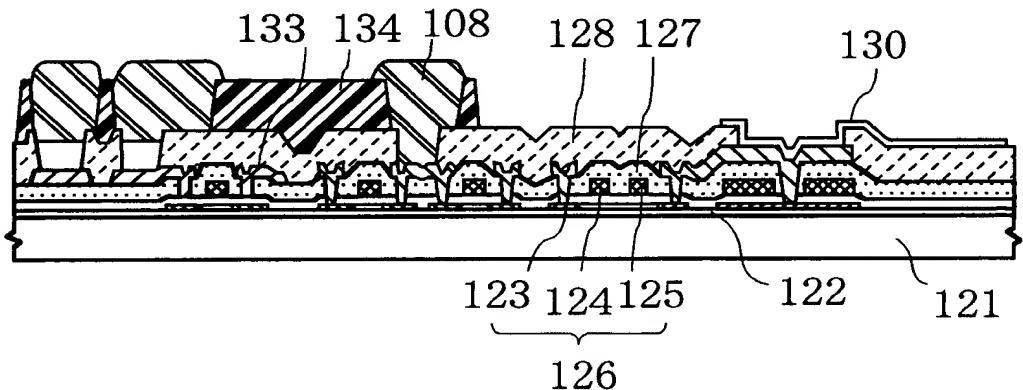
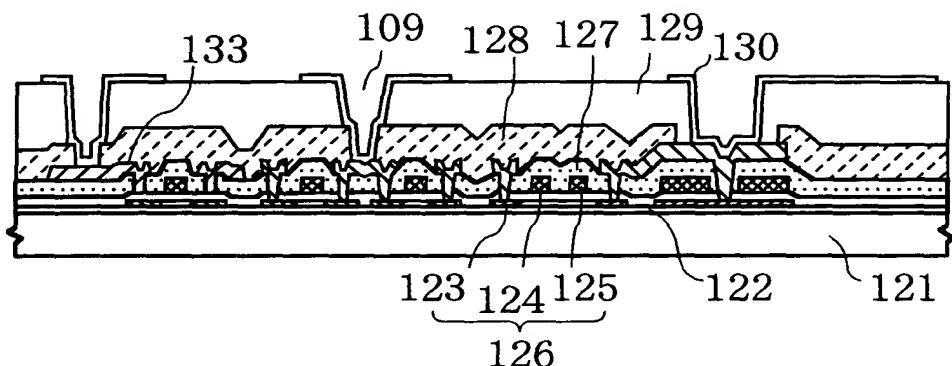
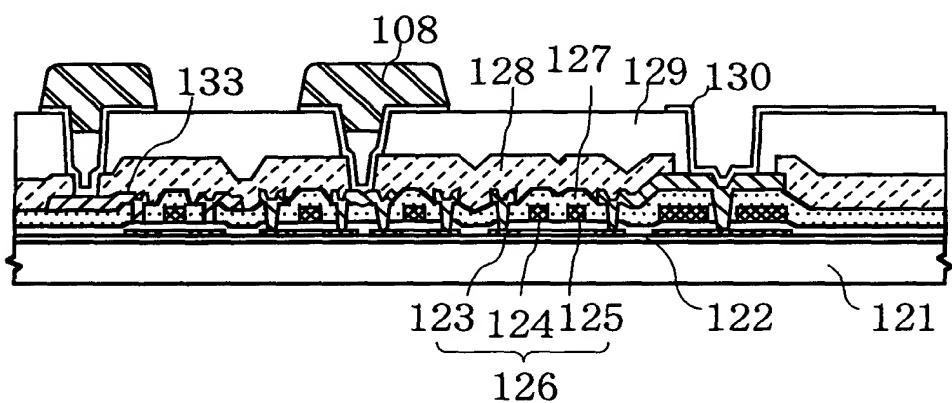


Fig. 12

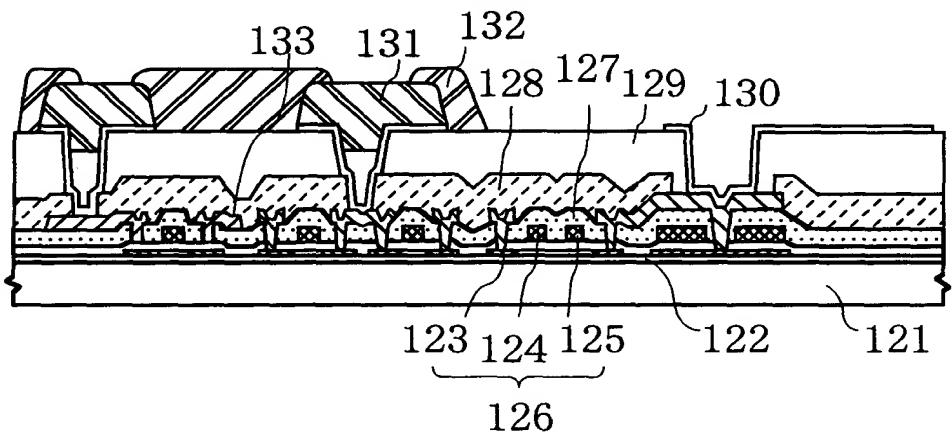
(A) After The Formation of ITO

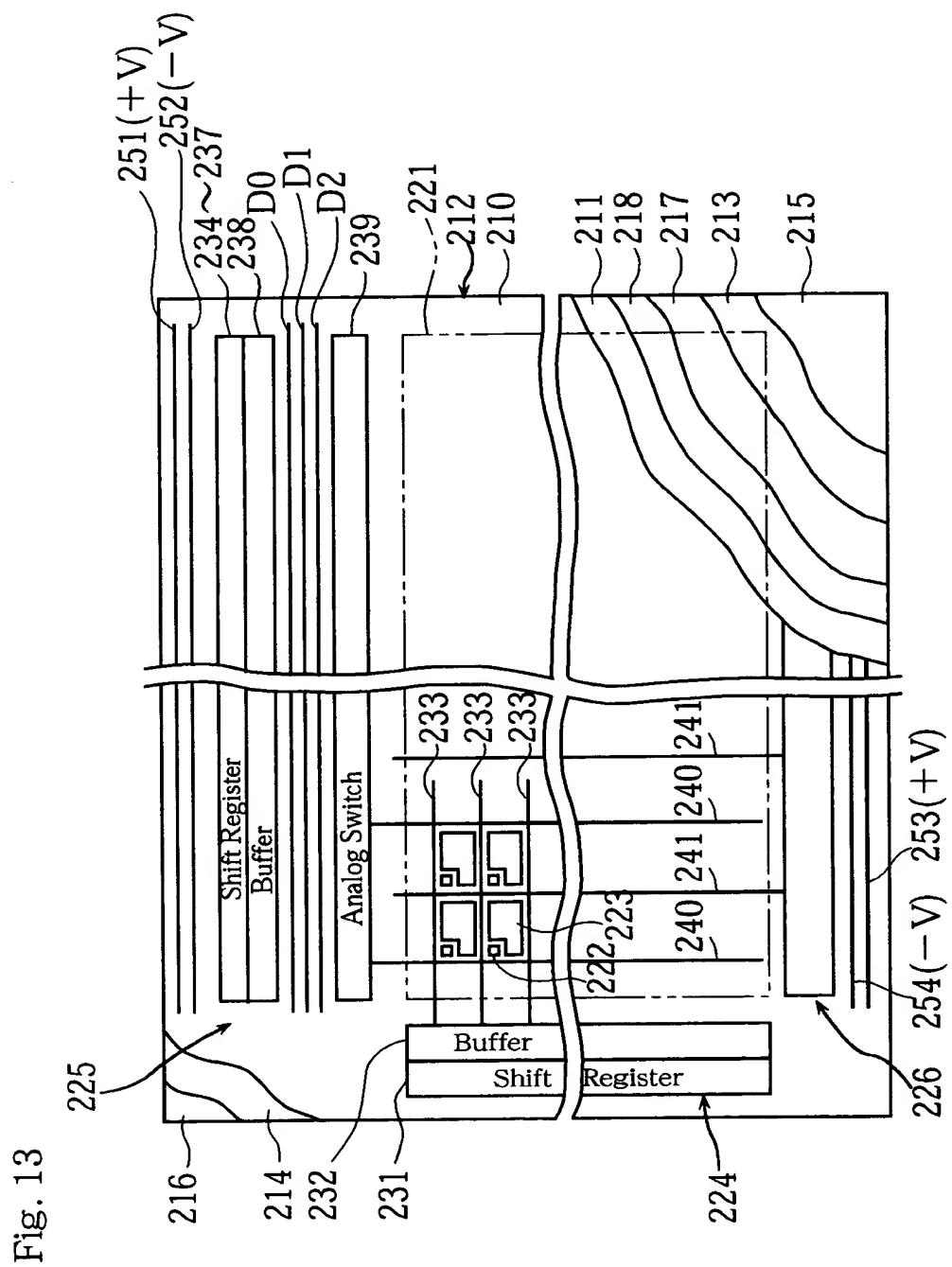


(B) After The Formation of Bus Line Electrode



(C) After The Formation of Printed Protective Film





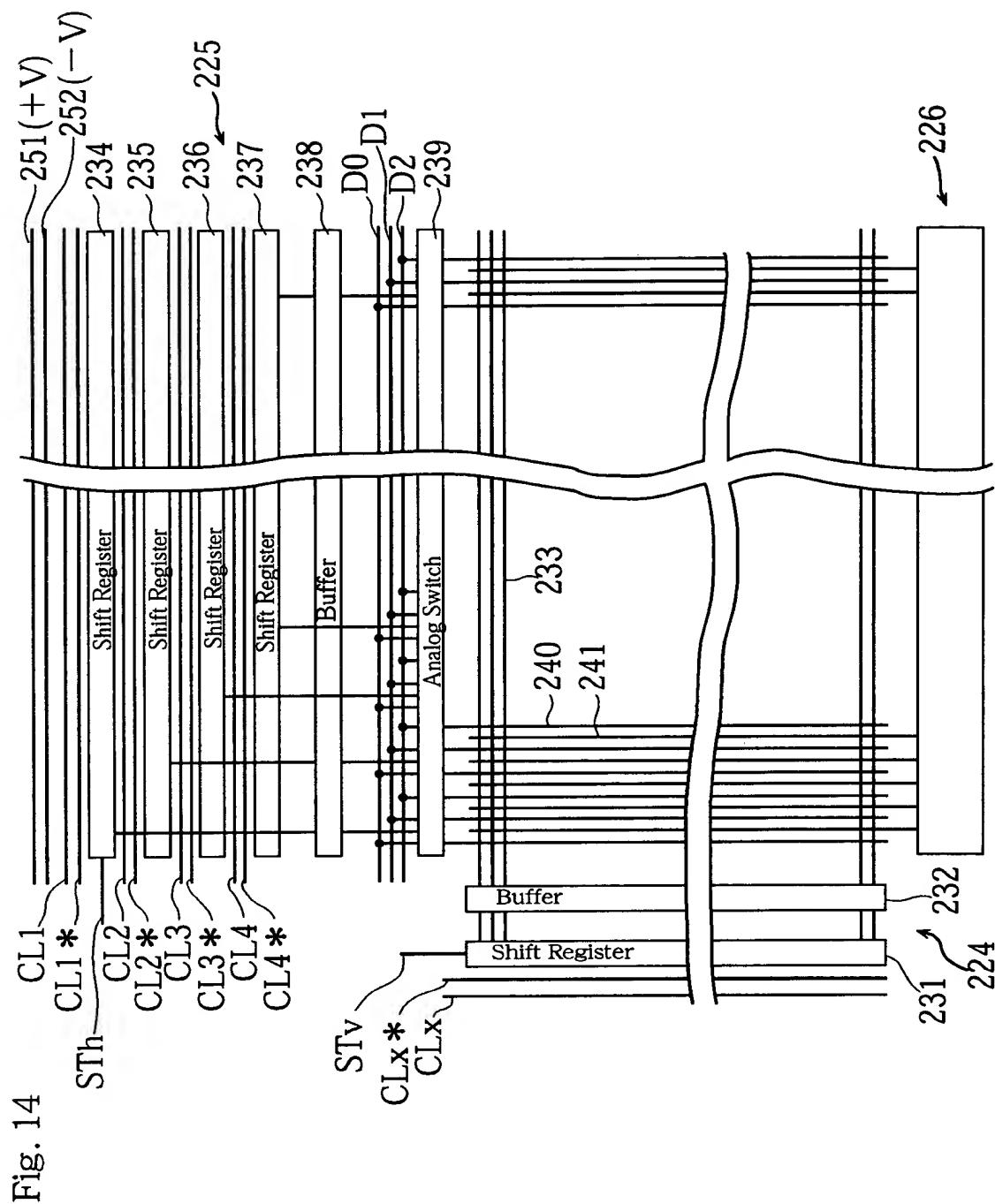


Fig. 15

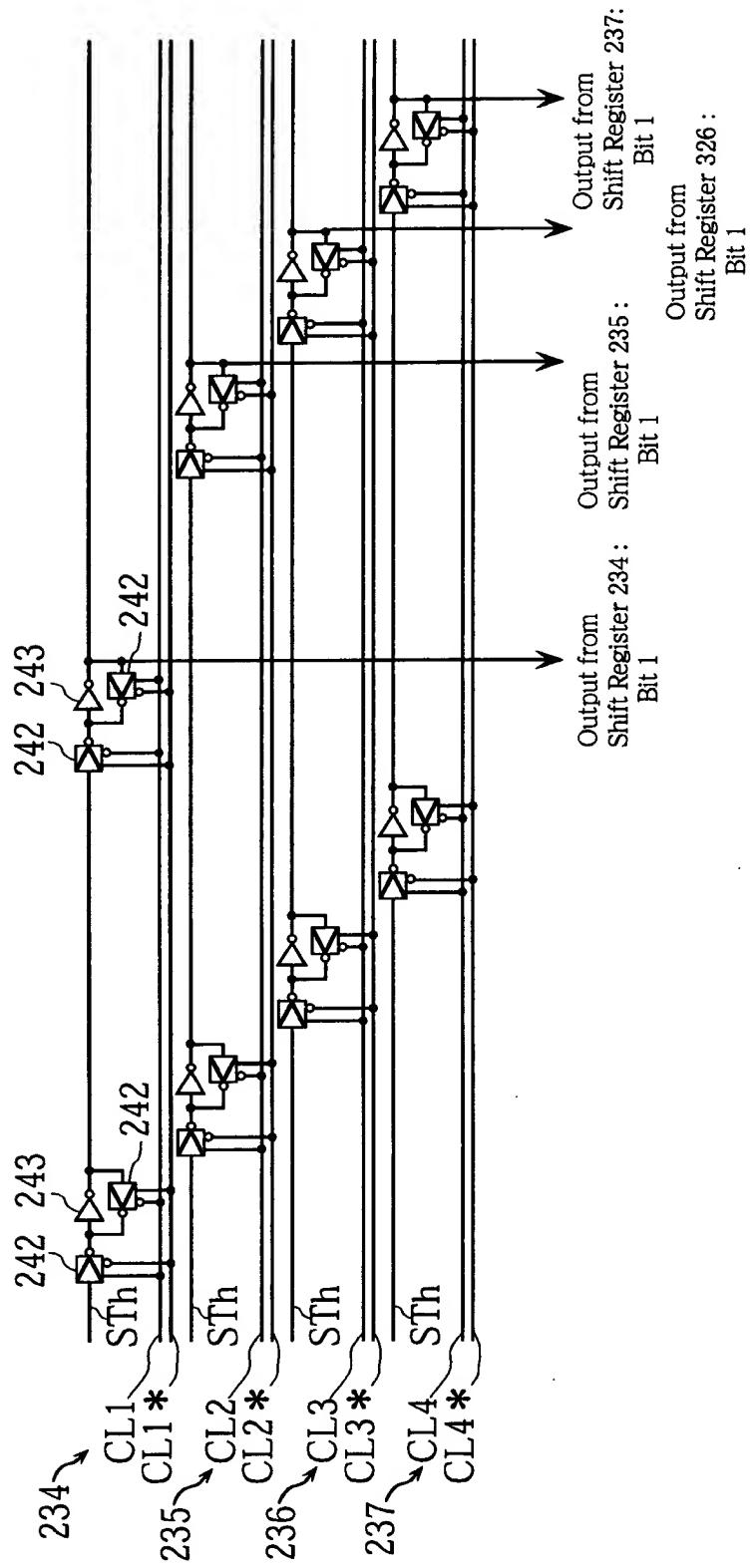


Fig. 16

TOP SECRET//COMINT

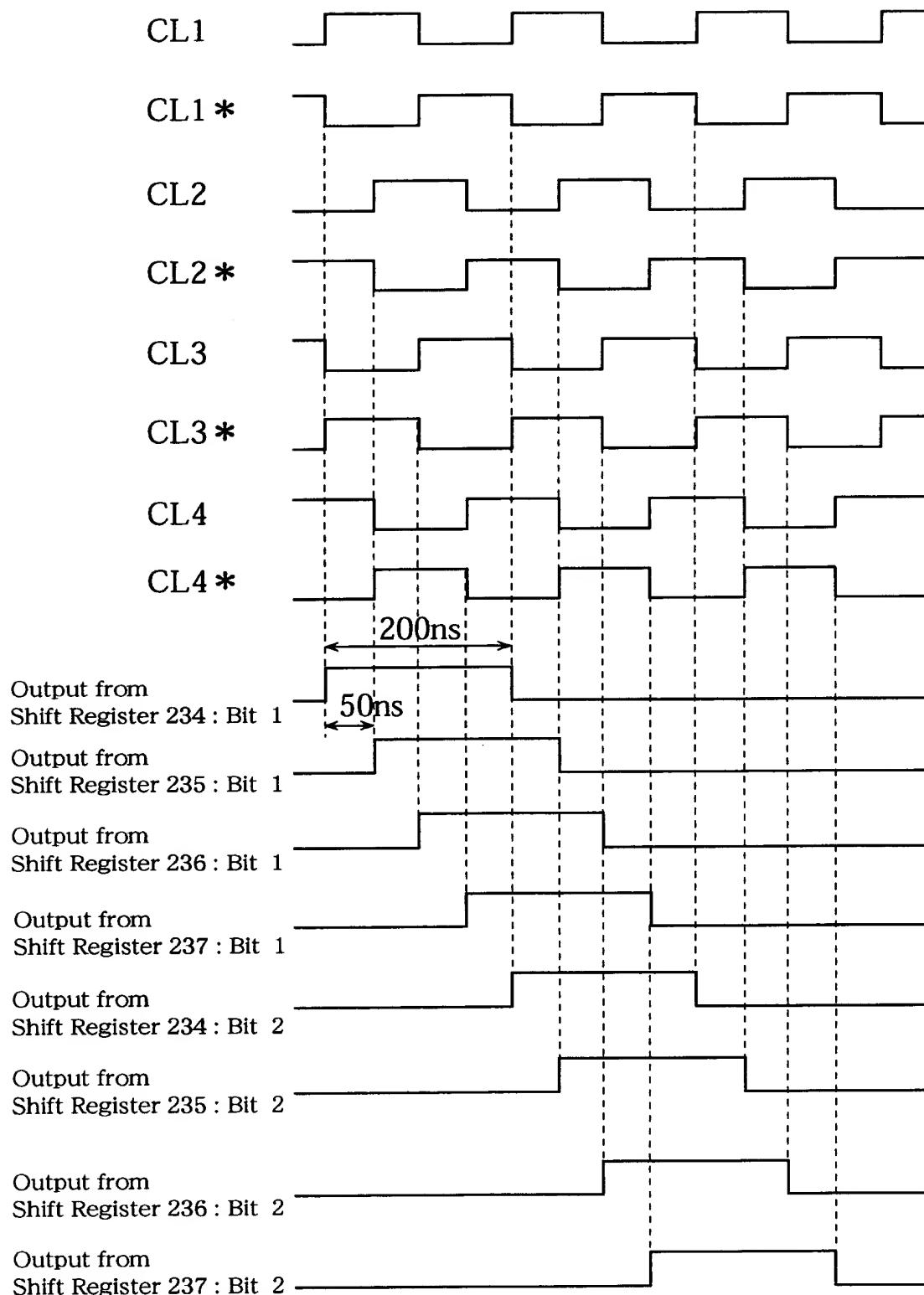


Fig. 17

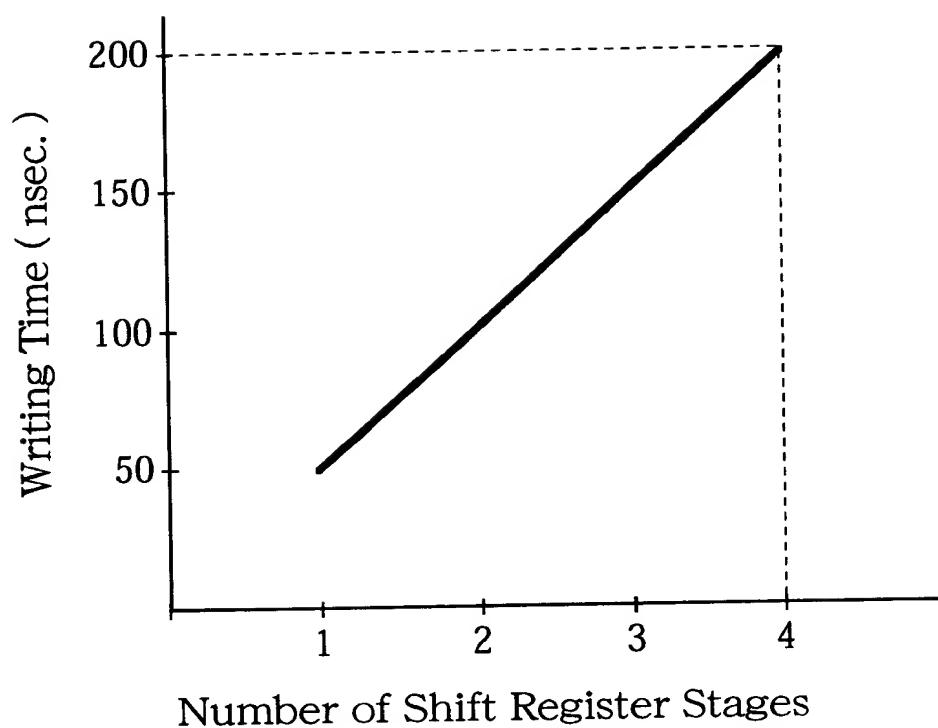


Fig. 18

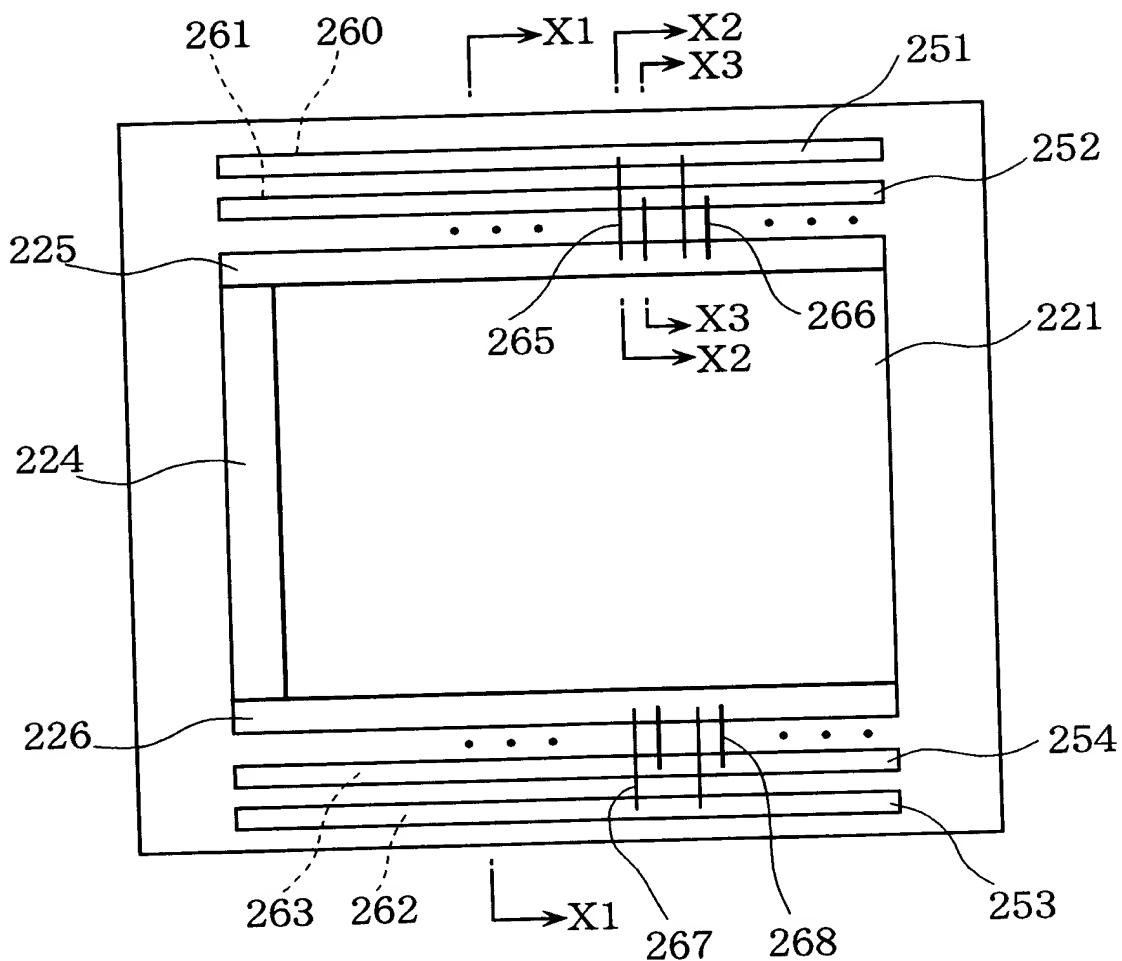


Fig. 19

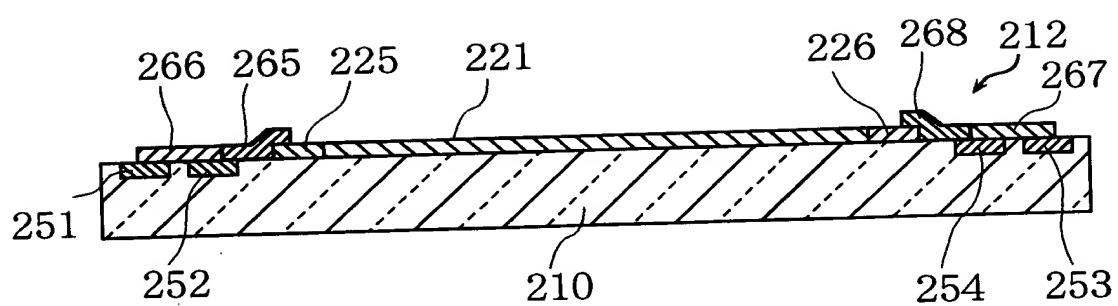


Fig. 20

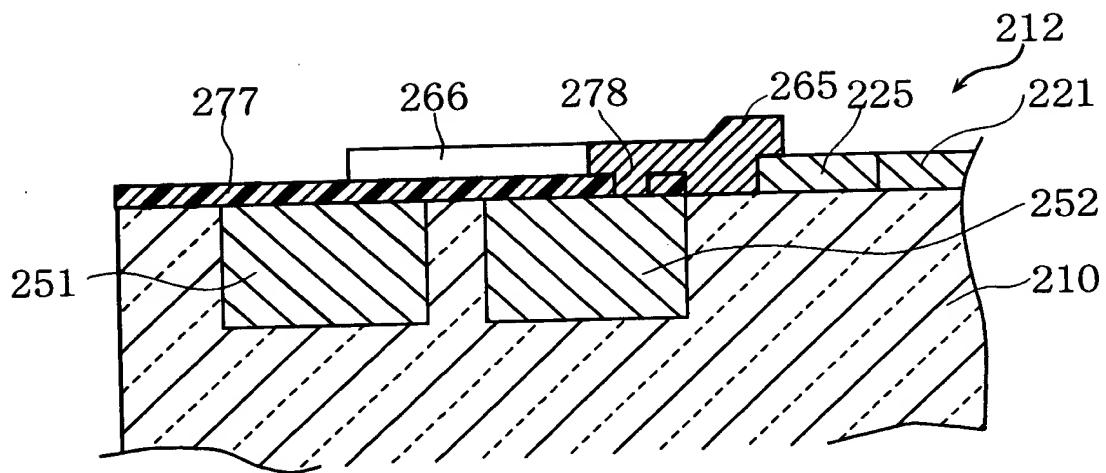
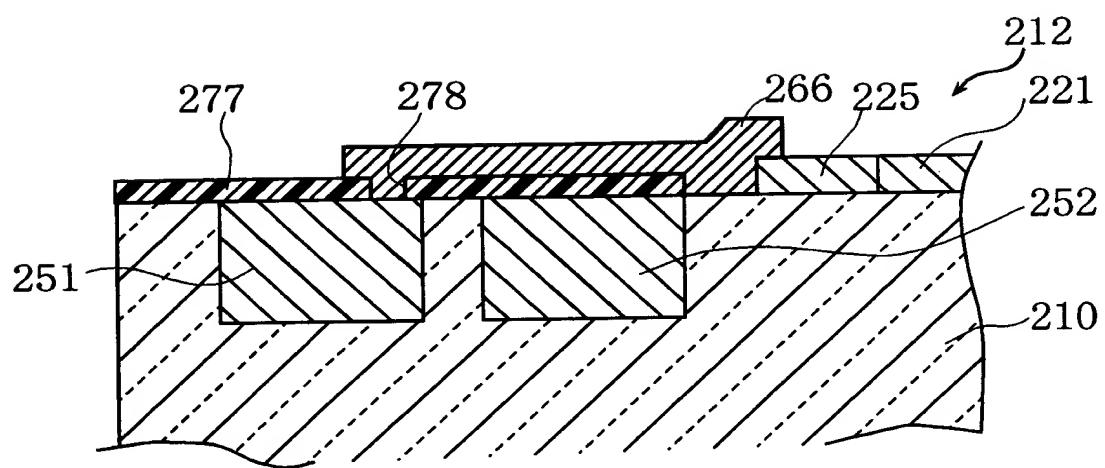


Fig. 21



4709050-3758313450

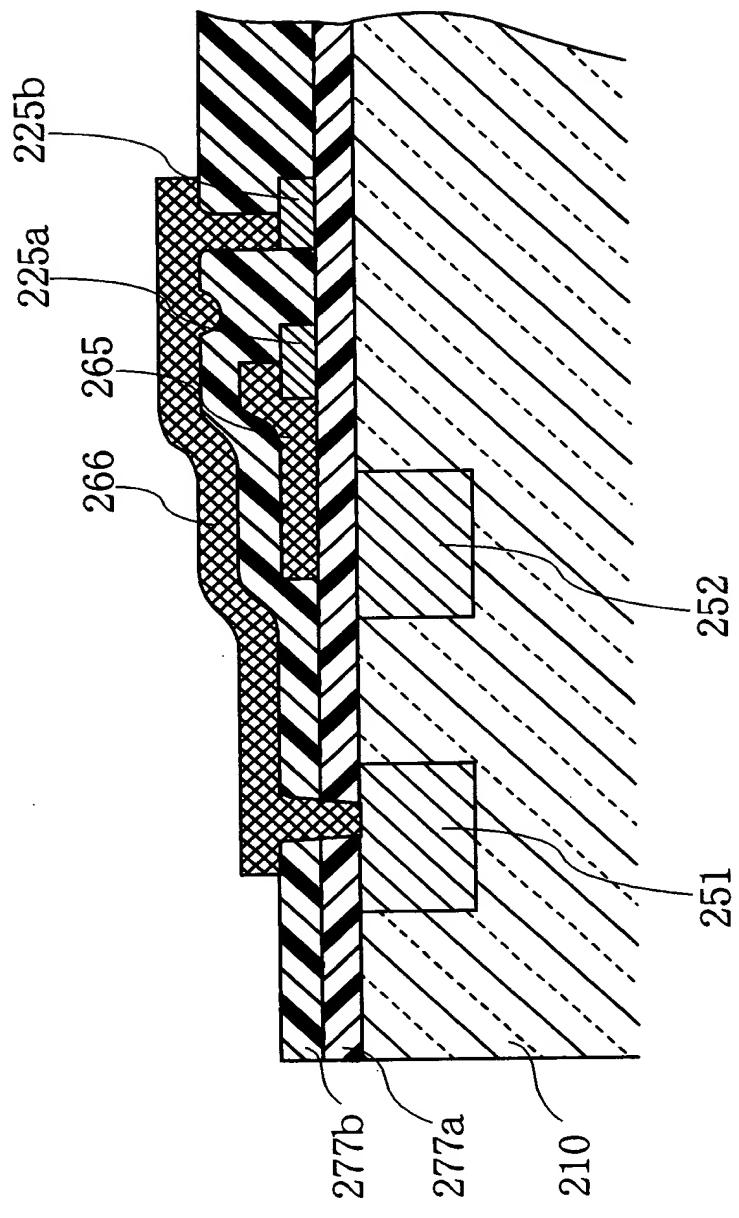


Fig. 22

Fig. 23

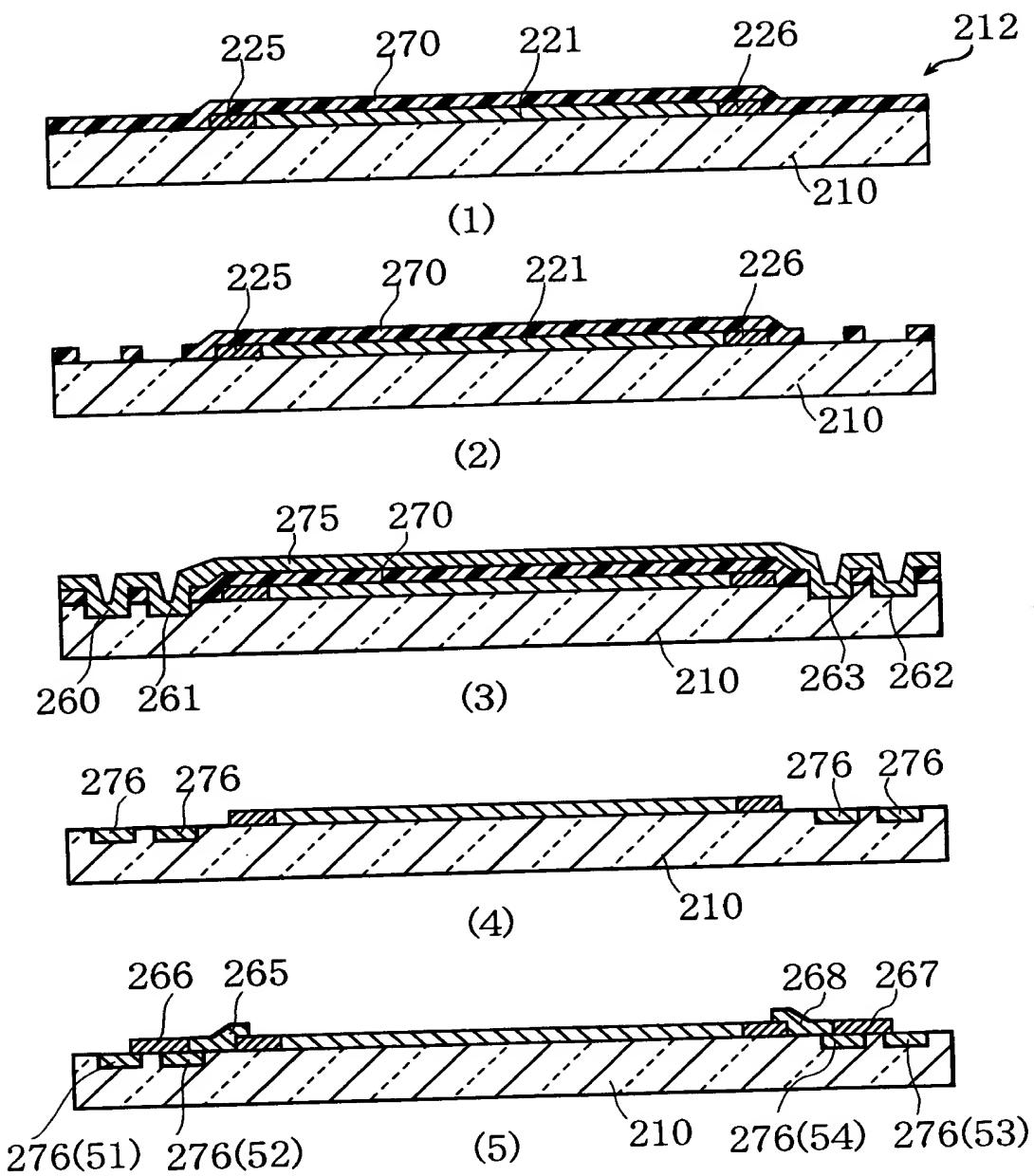


Fig. 24

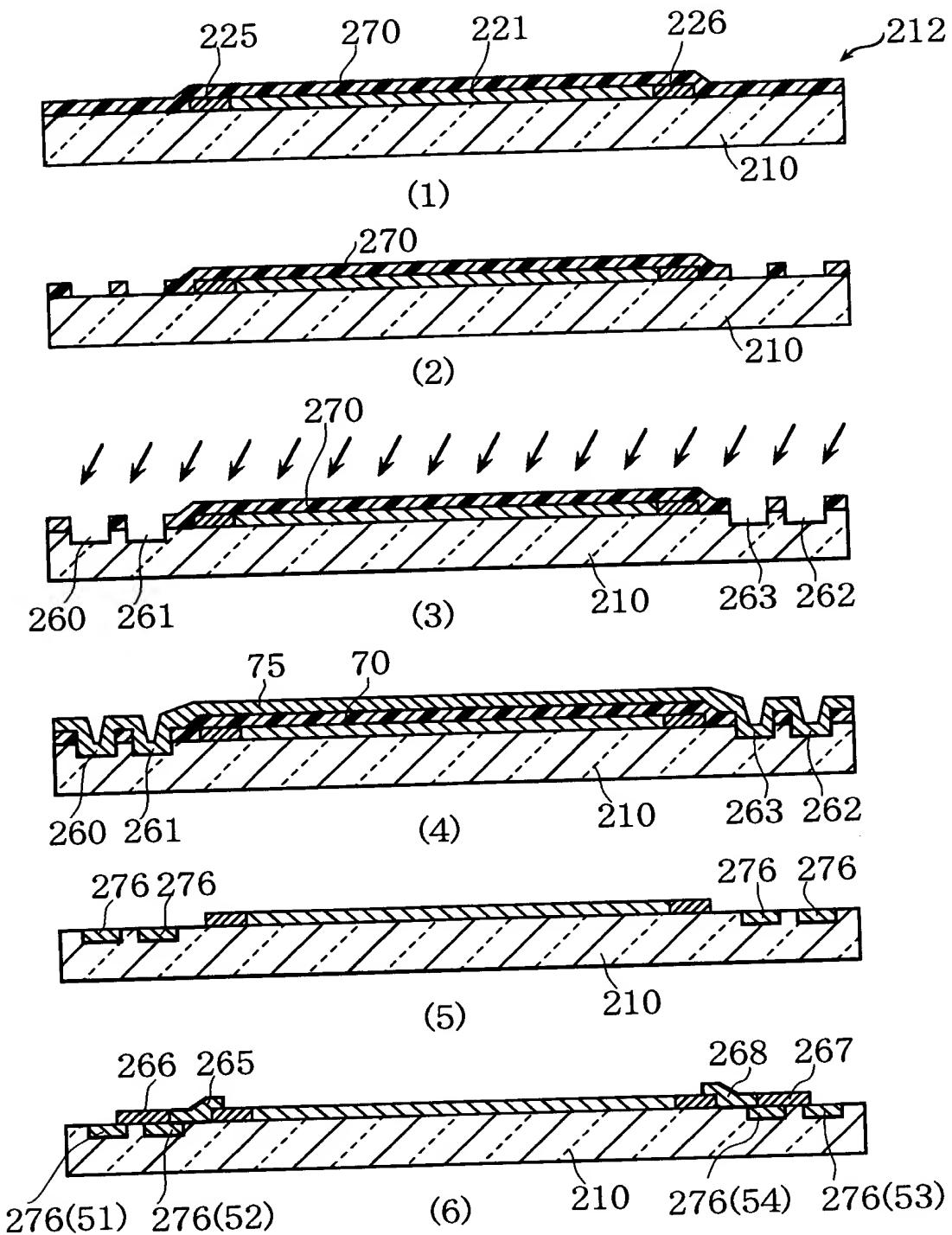


Fig. 25

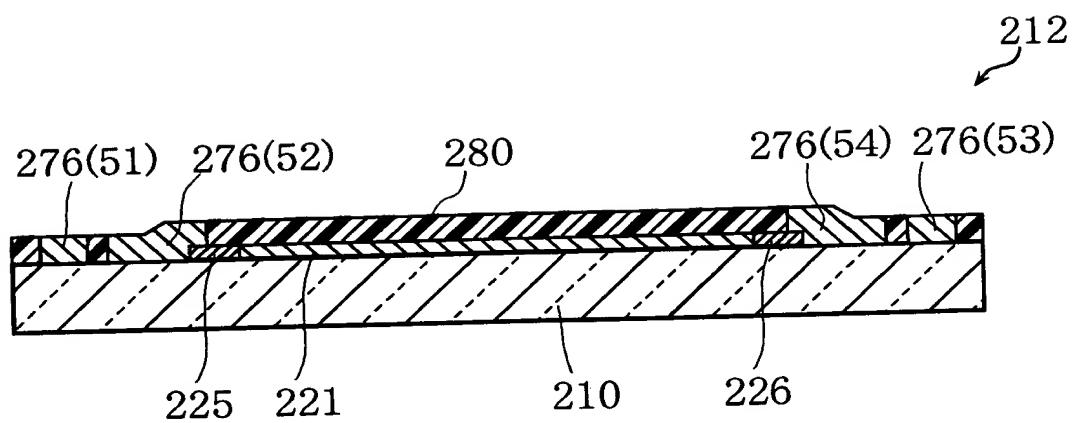


Fig. 26

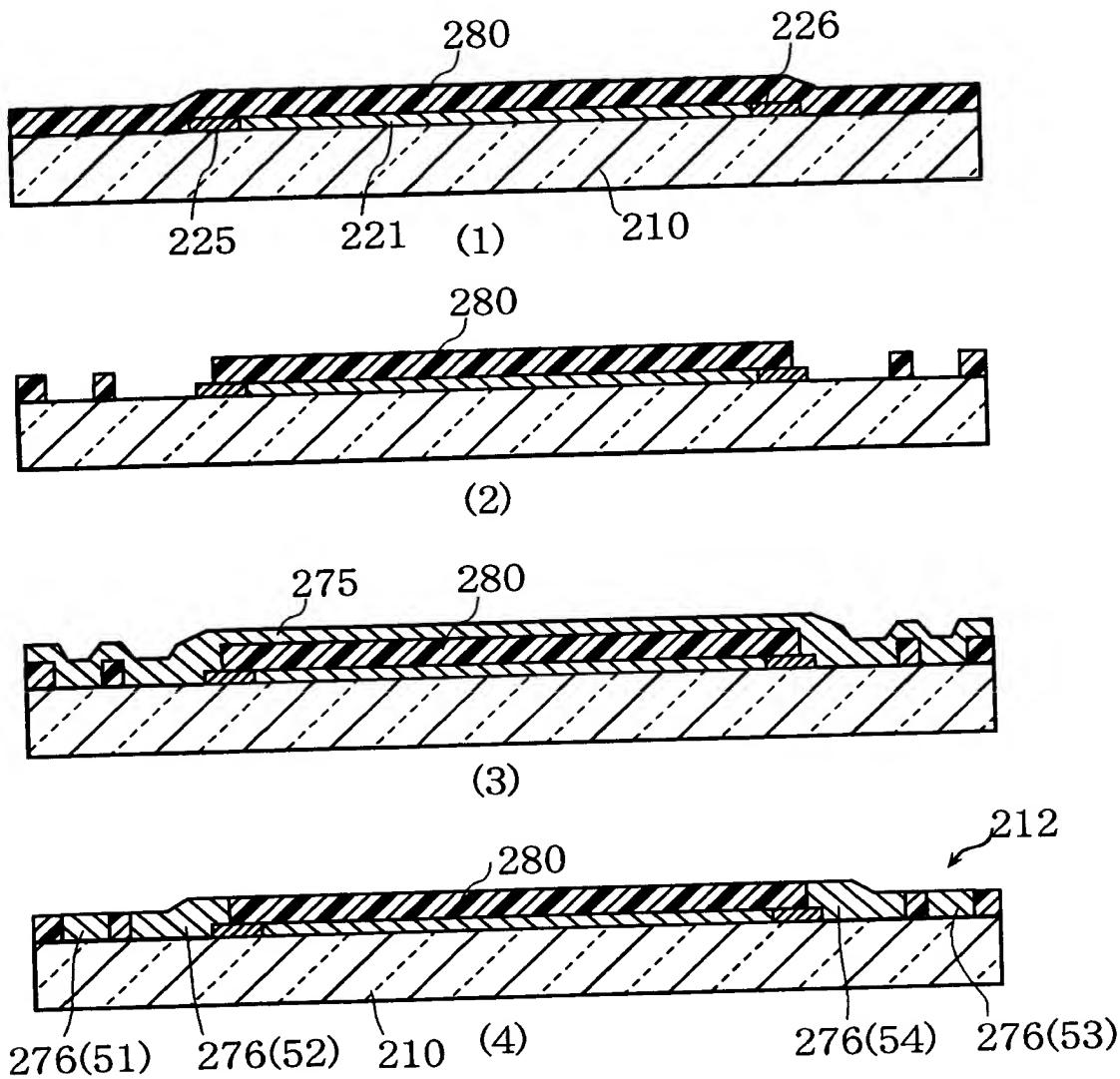


Fig. 27

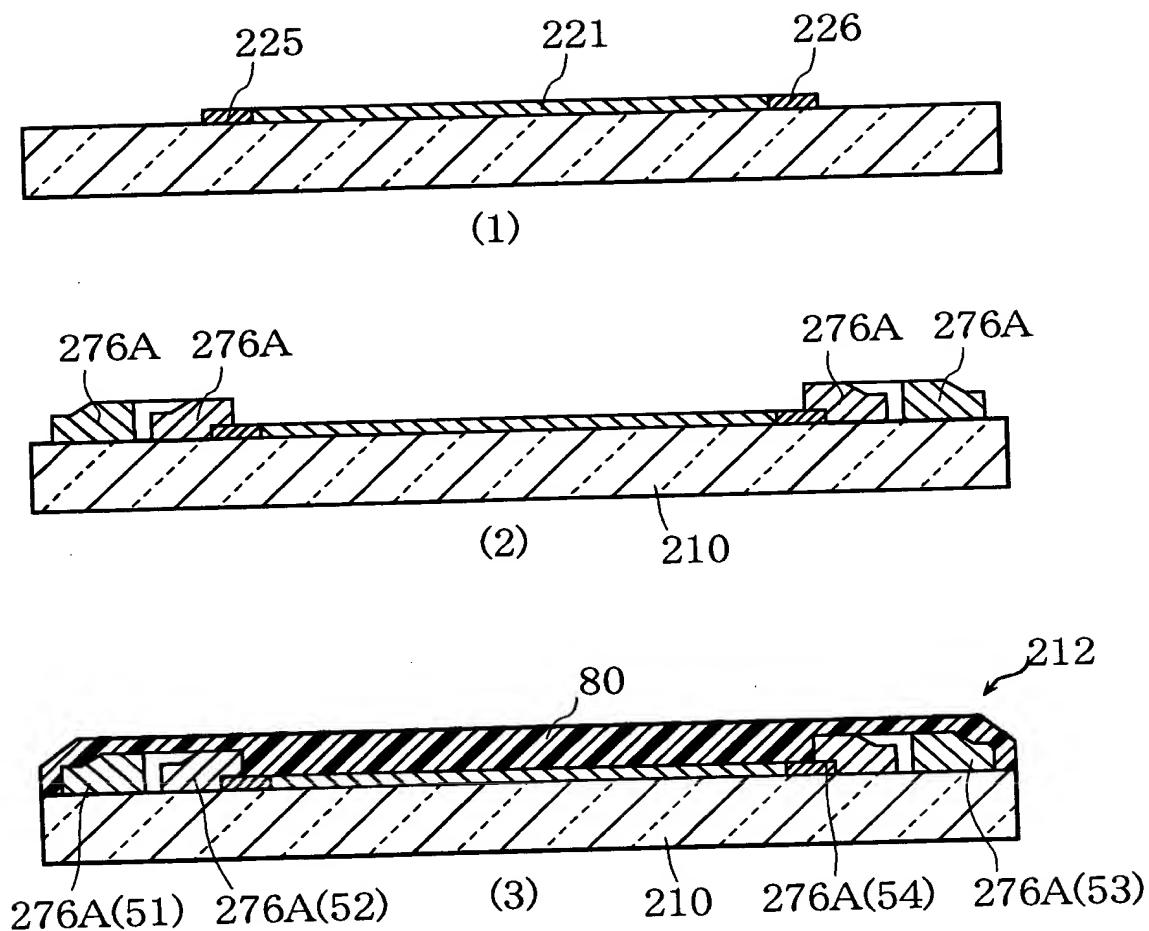


Fig. 28

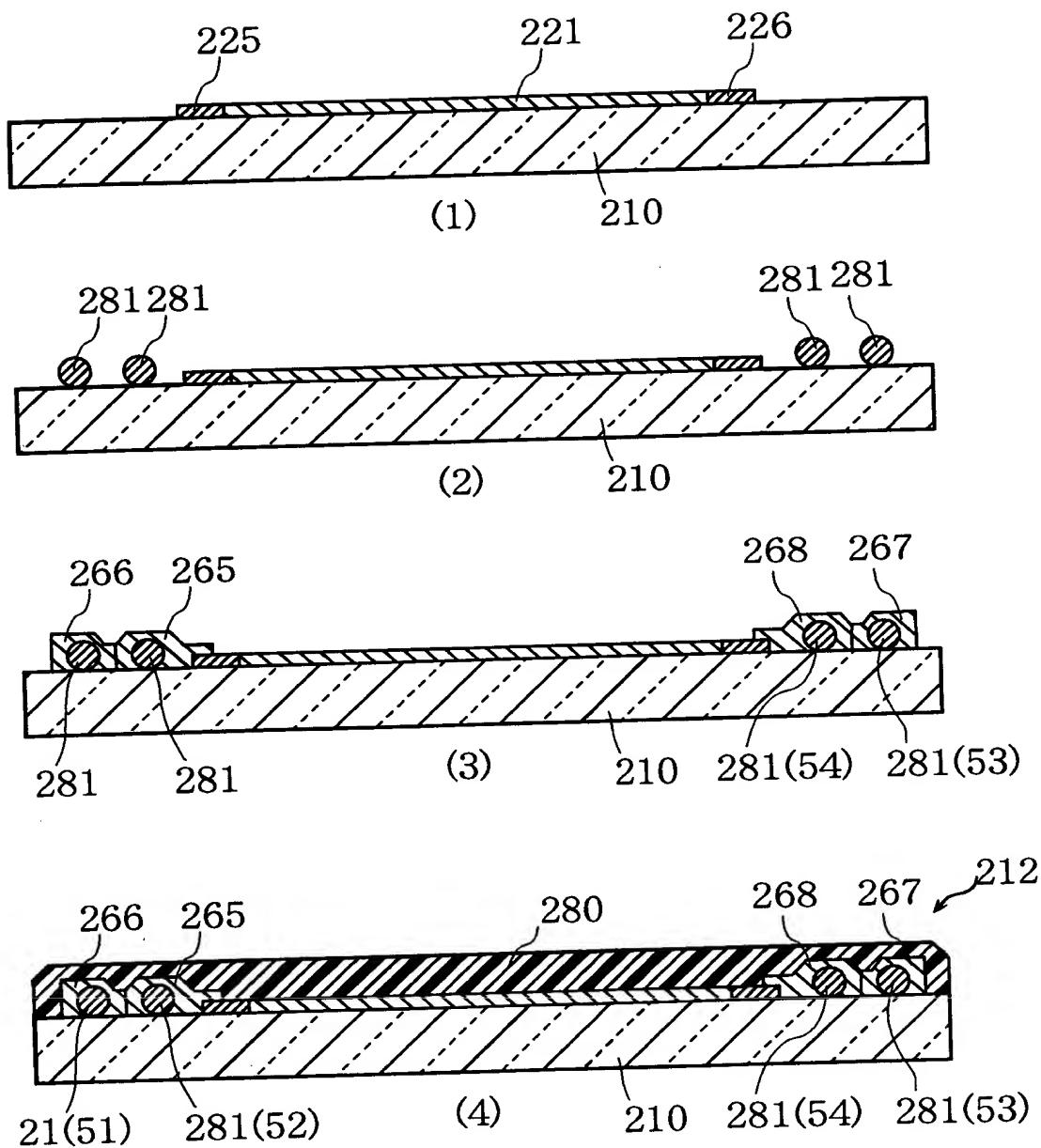


Fig. 29

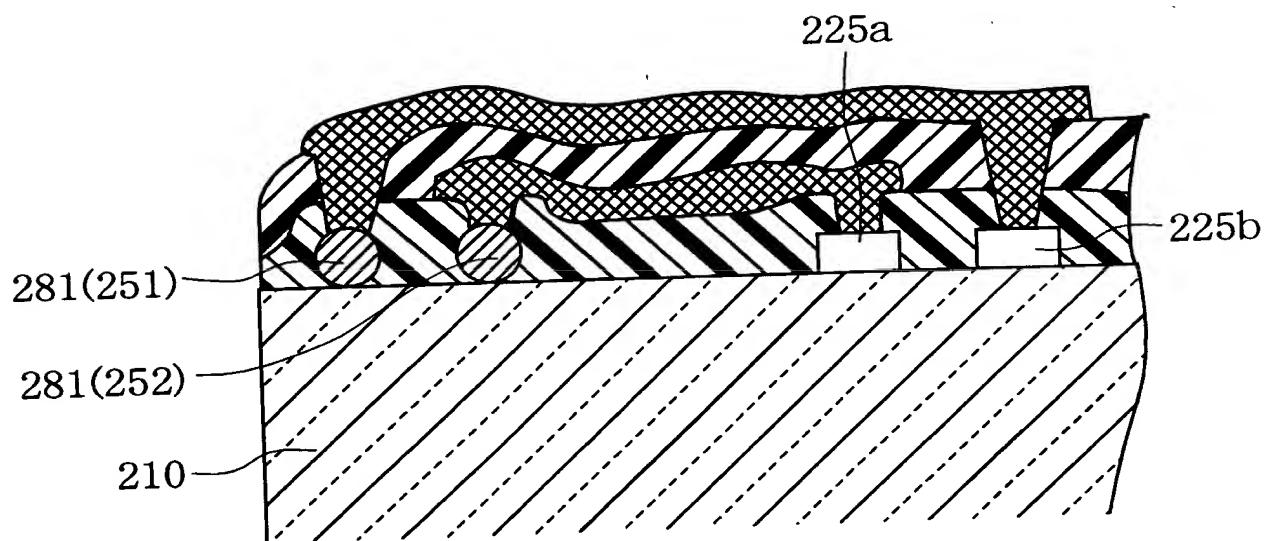


Fig. 30

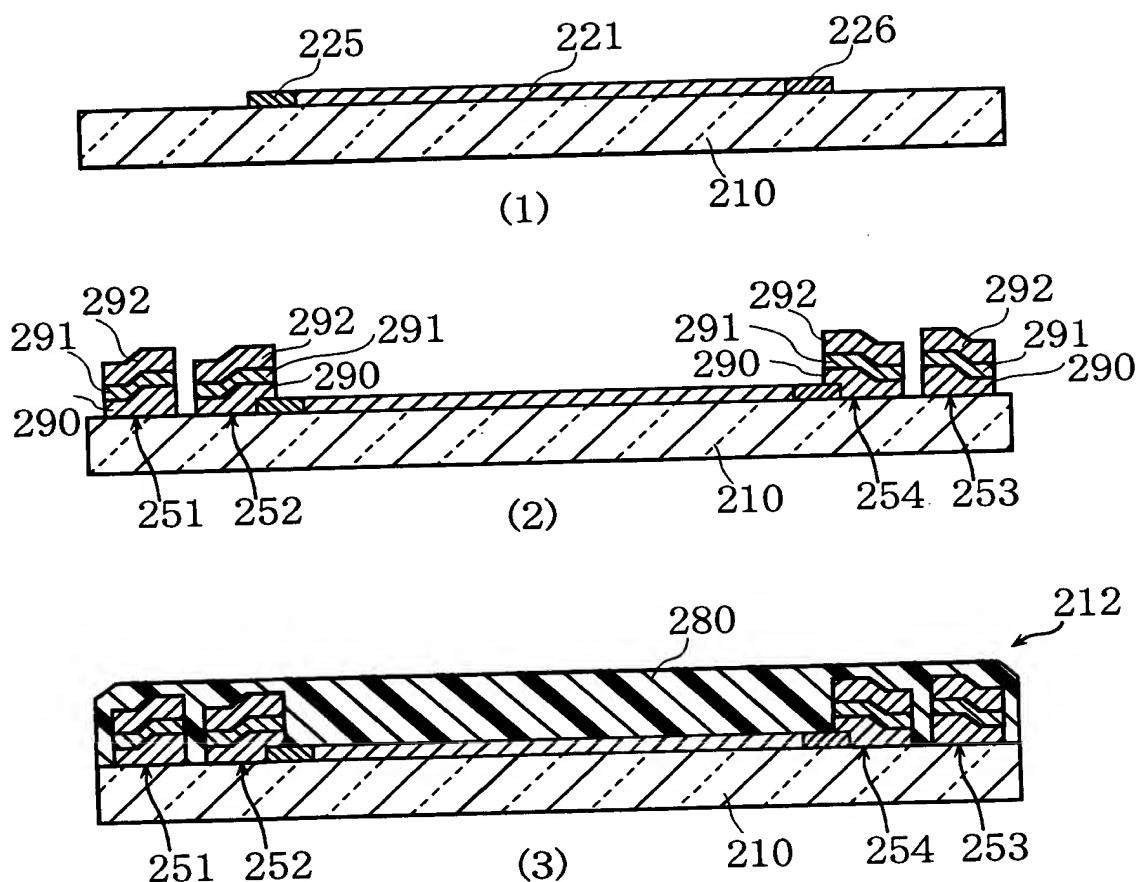
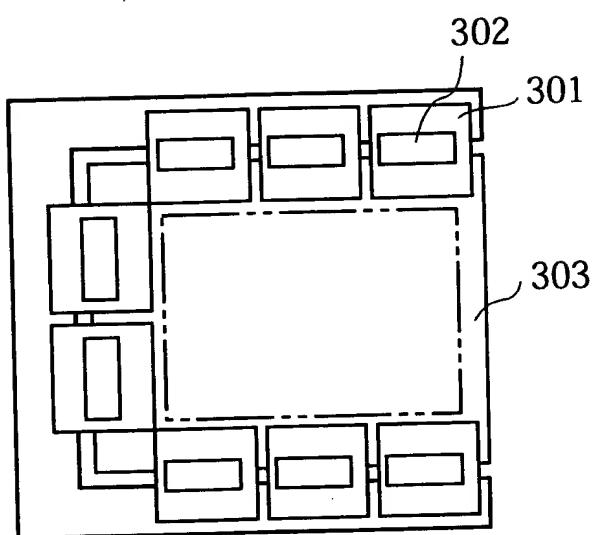


Fig. 31



09/831315

Fig. 32

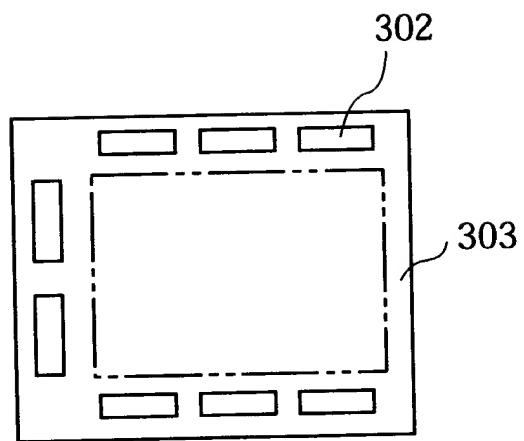


Fig. 33

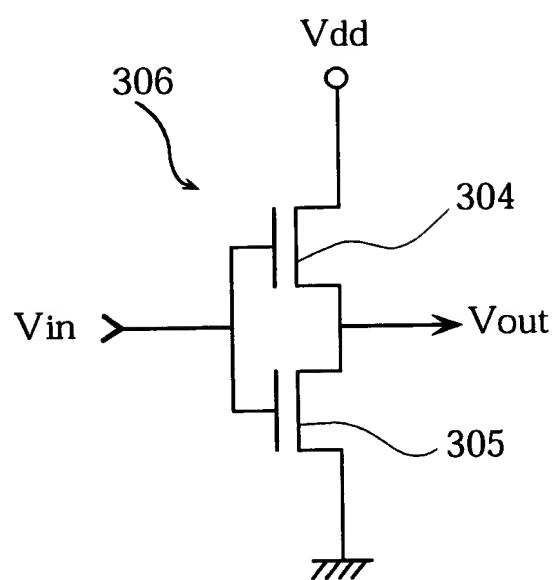
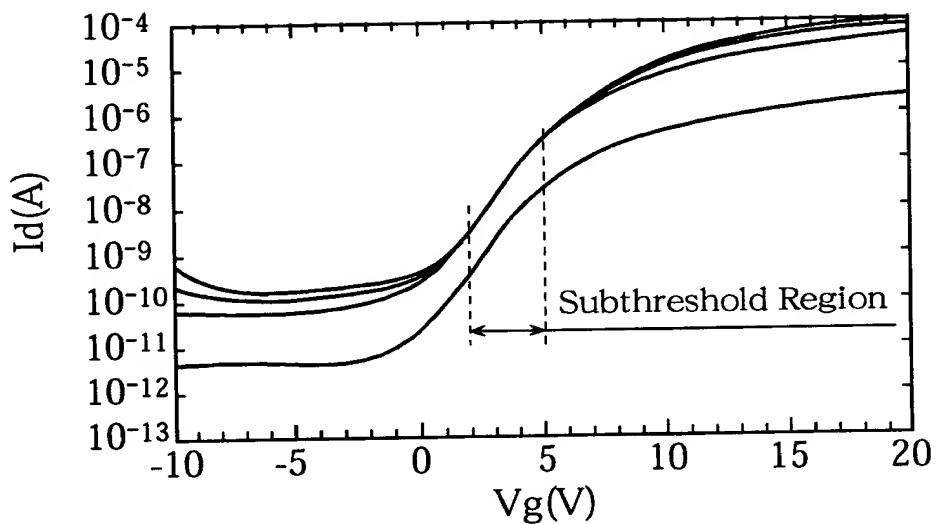


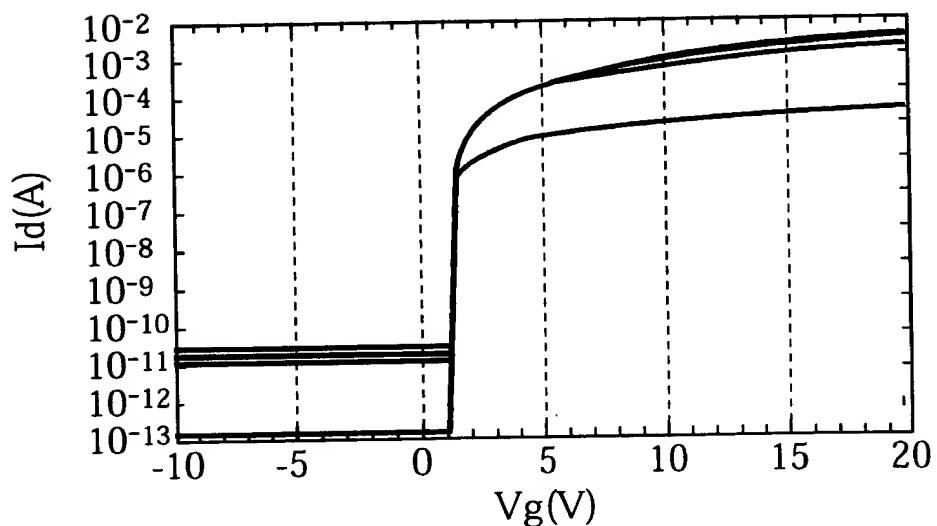
Fig. 34

(a)



Characteristics of Polysilicon TFT

(b)



Characteristics of Mos-Tr (Crystalline Silicon)

Fig. 35

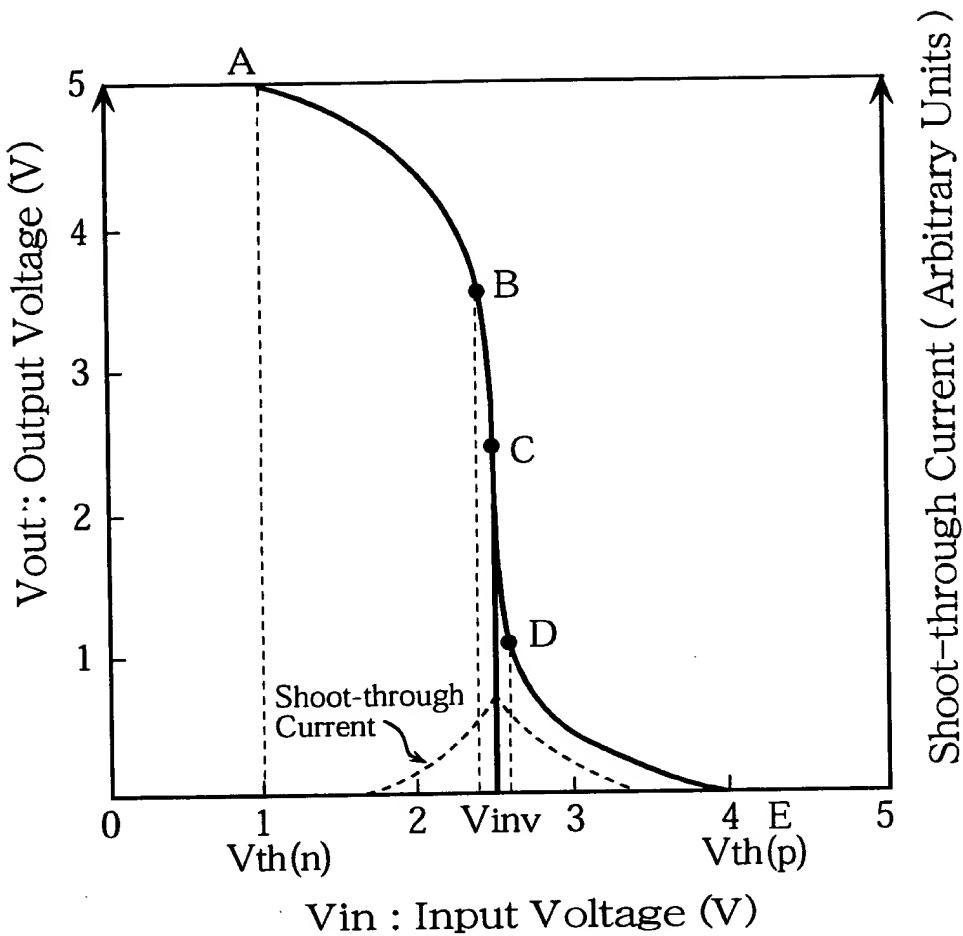


Fig. 36

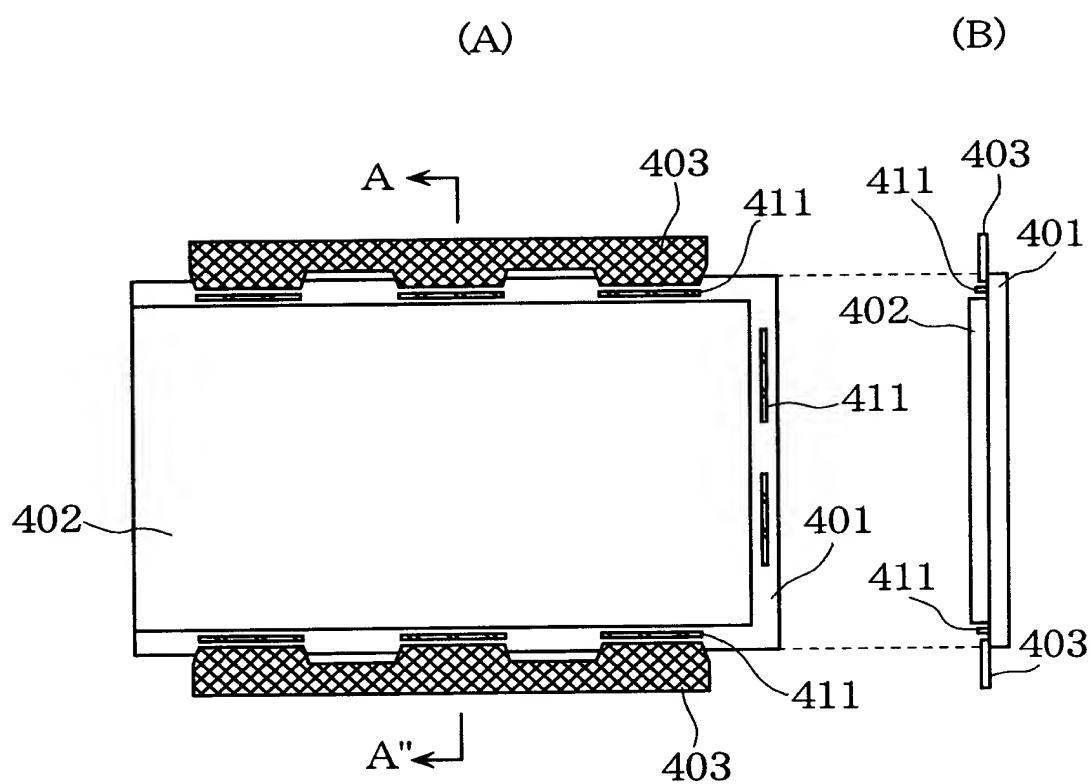


Fig. 37

